# 74HC20

# **Dual 4-input NAND gate**

Rev. 7 — 14 March 2024

**Product data sheet** 

### 1. General description

The 74HC20 is a dual 4-input NAND gate. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

#### 2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- · High noise immunity
- · Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards:
  - JESD8C (2.7 V to 3.6 V)
  - JESD7A (2.0 V to 6.0 V)
- · CMOS input levels
- · ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +80 °C and from -40 °C to +125 °C.

### 3. Ordering information

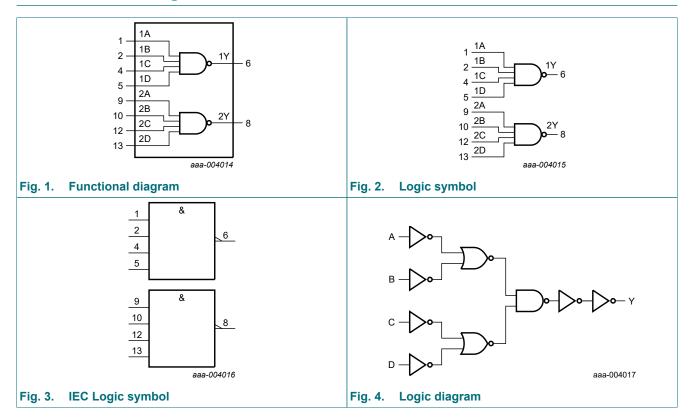
#### **Table 1. Ordering information**

Type number	Package				
	Temperature range	Name	Description	Version	
74HC20D	-40 °C to +125 °C		plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1	
74HC20PW	-40 °C to +125 °C		plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1	



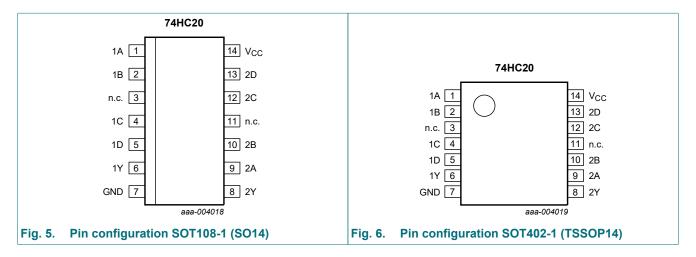
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# 4. Functional diagram



# 5. Pinning information

#### 5.1. Pinning



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### 5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1A, 1B, 1C, 1D	1, 2, 4, 5	data input
n.c.	3, 11	not connected
1Y	6	data output
GND	7	ground (0 V)
2Y	8	data output
2A, 2B, 2C, 2D	9, 10, 12, 13	data input
V <sub>CC</sub>	14	supply voltage

### 6. Functional description

#### Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care.

Input	Output			
nA	nB	nC	nD	nY
L	X	X	X	Н
X	L	Х	Х	Н
X	Х	L	Х	Н
X	Х	Х	L	Н
Н	Н	Н	Н	L

# 7. Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CC}$	supply voltage			-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	[1]	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	[1]	-	±20	mA
I <sub>O</sub>	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$		-	±25	mA
I <sub>CC</sub>	supply current			-	50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation		[2]	-	500	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>[2]</sup> For SOT108-1 (SO14) package: P<sub>tot</sub> derates linearly with 10.1 mW/K above 100 °C. For SOT402-1 (TSSOP14) package: P<sub>tot</sub> derates linearly with 7.3 mW/K above 81 °C.

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# 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	ns/V

### 9. Static characteristics

#### **Table 6. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>IH</sub> HIGH-level		V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V <sub>OH</sub>	HIGH-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O}$ = -5.2 mA; $V_{CC}$ = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V <sub>OL</sub>	LOW-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	2	-	20	-	40	μΑ
C <sub>I</sub>	input capacitance		-	3.5	-	-	-	-	-	pF

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# 10. Dynamic characteristics

#### **Table 7. Dynamic characteristics**

GND = 0 V;  $C_L$  = 50 pF; for test circuit see Fig. 8.

Symbol	Parameter	Conditions		25 °C -40 °C to +85 °C		-40 °C to +125 °C		Unit		
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>pd</sub>	propagation delay	nA, nB, nC, nD to nY; [1] see Fig. 7								
		V <sub>CC</sub> = 2.0 V	-	28	90	-	115	-	135	ns
		V <sub>CC</sub> = 4.5 V	-	10	18	-	23	-	27	ns
		V <sub>CC</sub> = 6.0 V	-	8	15	-	20	-	23	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	8	-	-	-	-	-	ns
t <sub>t</sub>	transition time	nY; see Fig. 7 [2]								
		V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns
C <sub>PD</sub>	power dissipation capacitance	per package; [3] $V_I = GND$ to $V_{CC}$	-	22	-	-	-	-	-	pF

<sup>[1]</sup>  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_i \times V_{CC}^2 \times f_0)$$
 where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

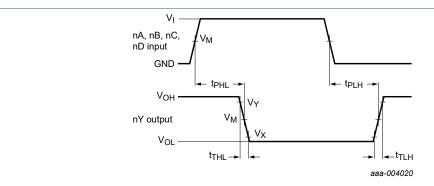
V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;  $\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

<sup>[2]</sup> t<sub>t</sub> is the same as t<sub>THL</sub> and t<sub>TLH</sub>.
[3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW):
P<sub>D</sub> = C<sub>PD</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>i</sub> x N + ∑(C<sub>L</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>o</sub>) where:

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#### 10.1. Waveforms and test circuit



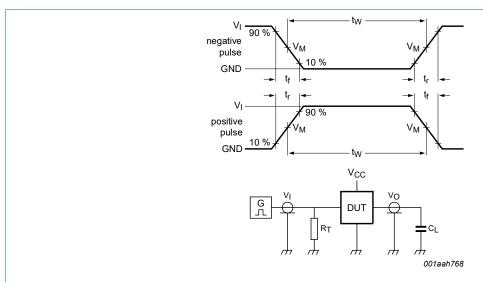
Measurement points are given in Table 8.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

Fig. 7. Waveforms showing the input (nA, nB, nC, nD) to output (nY) propagation delays and the output transition times

**Table 8. Measurement points** 

Input	Output			
$V_{M}$	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>	
0.5V <sub>CC</sub>	0.5V <sub>CC</sub>	0.1V <sub>CC</sub>	0.9V <sub>CC</sub>	



Test data is given in Table 9.

Definitions test circuit:

 $R_T$  = termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

 $C_L$  = load capacitance including jig and probe capacitance.

Fig. 8. Test circuit for measuring switching times

Table 9. Test data

Input		Load	Test
V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	CL	
V <sub>CC</sub>	6.0 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>

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# 11. Package outline

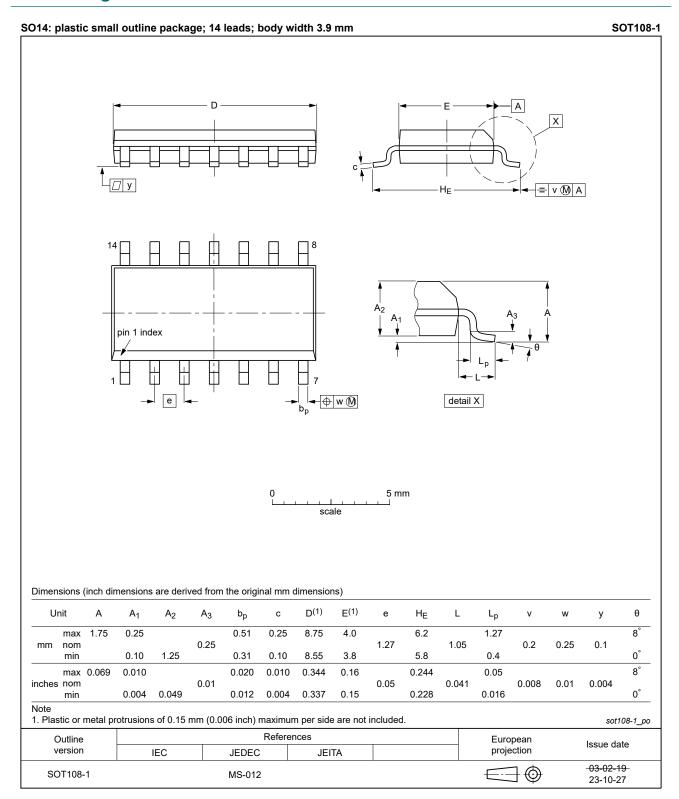


Fig. 9. Package outline SOT108-1 (SO14)

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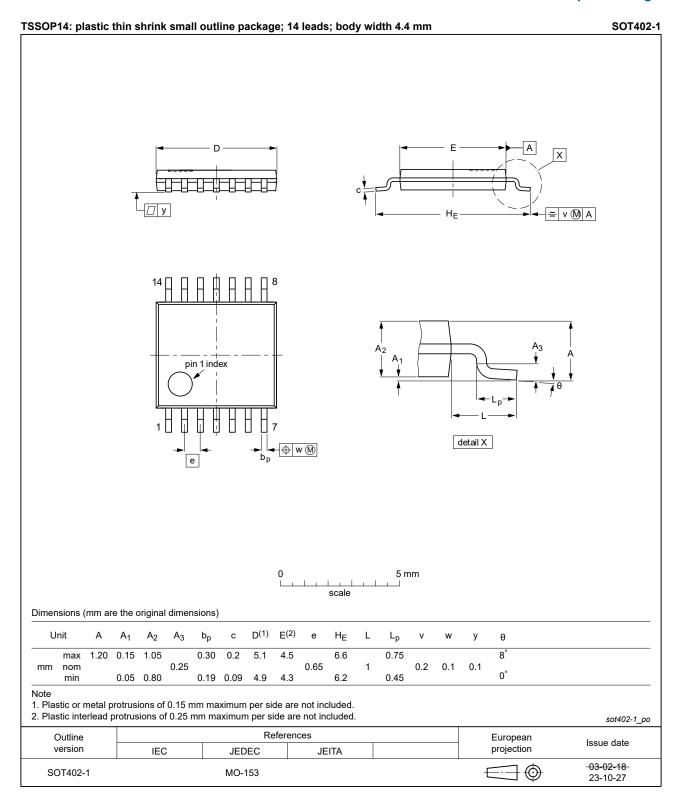


Fig. 10. Package outline SOT402-1 (TSSOP14)

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### 12. Abbreviations

#### **Table 10. Abbreviations**

Acronym	Description	
CDM	Charged Device Model	
CMOS	Complementary Metal Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
HBM	ıman Body Model	
TTL	ransistor-Transistor Logic	

# 13. Revision history

#### **Table 11. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC20 v.7	20240314	Product data sheet	-	74HC_HCT20 v.6			
Modifications:	MO-153.	<ul> <li>Fig. 9, Fig. 10: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153.</li> <li>Section 2: ESD specification updated according to the latest JEDEC standard.</li> </ul>					
74HC20 v.6	20210208	Product data sheet	-	74HC_HCT20 v.5			
Modifications:	<ul> <li>Section 1 and Section 2 updated.</li> <li>Type number 74HCT20D (SOT108-1 / SO14) removed.</li> <li>Type numbers 74HC20DB and 74HCT20DB (SOT337-1 / SSOP14) removed.</li> <li>Section 7: Derating values for P<sub>tot</sub> total power dissipation updated.</li> </ul>						
74HC_HCT20 v.5	20190327	Product data sheet	-	74HC_HCT20 v.4			
Modifications:	Nexperia. • Legal texts h	of this data sheet has been r have been adapted to the ne r 74HCT20PW (SOT402-1/	ew company name whe	rith the identity guidelines of re appropriate.			
74HC_HCT20 v.4	20151118	Product data sheet	-	74HC_HCT20 v.3			
Modifications:	Type numbe	rs 74HC20N and 74HCT20I	N (SOT27-1) removed.				
74HC_HCT20 v.3	20120903	Product data sheet	-	74HC_HCT20_CNV v.2			
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>						
74HC_HCT20_CNV v.2	19970828	Product specification	-	74HC_HCT20_1			

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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